# TGS2351-SM DC – 6 GHz High Power SPDT Switch

# Applications

High Power Switching





QFN 4x4mm 24L

#### **Functional Block Diagram**



- Frequency Range: DC 6 GHz
- Power Handling: up to 40 W
- Insertion Loss: < 1 dB
- Isolation: -40 dB typical
- Switching Speed: 50 ns
- Control Voltages: 0 V/-40 V
- Dimensions: 4.0 x 4.0 x 1.43 mm

#### **General Description**

The TriQuint TGS2351-SM is a Single-Pole, Double-Throw (SPDT) Packaged Switch. The TGS2351-SM operates from DC to 6 GHz and is designed using TriQuint's 0.25um GaN on SiC production process.

The TGS2351-SM typically provides up to 40 W input power handling at control voltages of 0/-40 V. This switch maintains low insertion loss < 1 dB, and high isolation -40 dB typical.

The TGS2351-SM is ideally suited for High Power Switching application.

Lead-free and RoHS compliant

Evaluation Boards are available upon request.



### **Pin Configuration**

Pin #	Symbol
1, 2, 5, 6, 7, 9, 12, 13, 18, 19, 22, 24, 25	GND
3 and 4	RF In
8	Vc2
10 and 11	RF Out2
14, 15, 16, 17	N/C
20 and 21	RF Out1
23	Vc1

Part No.	ECCN	Description
TGS2351-SM	EAR99	DC – 6 GHz High Power SPDT Switch

**Ordering Information** 



# **Specifications**

# Absolute Maximum Ratings

Rating	
- 50 V	
-1 to 7.8 mA	
10 W	
47 dBm	
40 dBm	
40 dbiii	
275 °C	
260 °C	
200 C	
-55 to 150 °C	

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

# **Recommended Operating Conditions**

Parameter	Min	Typical	Max	Units
Vc1		-40 / 0		V
Vc2		0 / -40		V
Ic1 / Ic2		-0.4 to 0.1		mA

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

# **Electrical Specifications**

Test conditions unless otherwise noted:  $25^{\circ}$ C, Vc1 = -40/0 V, Vc2 = 0/-40 V, see Function Table at Application Circuit on page 7

Parameter	Min	Typical	Max	Units
Operational Frequency Range	DC		6	GHz
Control Current (Ic1/ Ic2)	-1		0.1	mA
Insertion Loss (On-State): DC to 5 GHz		0.5	1	dD
Insertion Loss (On-State): 6 GHz		0.8	1.2	ub
Input Return Loss – On-State (Common Port RL)	12	20		dB
Output Return Loss – On-State (Switched Port RL)	12	20		dB
Isolation (Off-State)		-40	-31	dB
Output Return Loss – Off-Sate (Isolated Port RL)		2.5		dB
Input Power <sup>1/</sup>		46		dBm
Output Power @ Pin = 46dBm, 1-6GHz		45		dBm
Insertion Loss Temperature Coefficient		-0.003		dB/°C
Output TOI @ Pin = 23 dBm		50		dBm
Switching Speed – On <sup>2/</sup>		50		ns
Switching Speed – Off <sup>2/</sup>		50		ns

1/ The Input Power will be reduced if < 10 MHz.

2/ These Switching Speed dependent on Switch Driver circuit to deliver Vc = 0/-40 V. The rise and fall time of the Switch Driver which was used to perform for this data is 35 ns, as shown on page 6. For further technical information, see <u>GaN SPDT Switch Drivers</u> <u>Application Note</u>



# **Specifications (cont.)**

# **Thermal and Reliability Information**

Parameter	Condition	Rating
Thermal Resistance, $\theta_{JC}$ , measured to back of package	Tbase = $85 ^{\circ}C$	$\theta_{\rm JC} = 6.1 \ ^{\circ}{\rm C/W}$
Channel Temperature (Teh) and Madian Lifetime (Tm)	Tbase = $85 \degree C$ , Vc1 = 0 V, Vc2 = -40	Tch = 118 °C
Channel Temperature (TCh), and Median Lifetime (Thi)	V, $Pin = 40$ W, $Pdiss = 5.3$ W	Tm = 1.4 E+9 Hours





#### **Typical Performance**













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# **Typical Performance (cont.)**













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# Typical Performance (cont.)







Switching Speed – On 50 ns Vc = 0/-40 V, Freq = 3 GHz, Pin = 30 dBm, +25  $^{\circ}\text{C}$ 



Switching Speed - Off 50 ns Vc = 0/-40 V, Freq = 3 GHz, Pin = 30 dBm, +25  $^{\circ}C$ 

# TGS2351-SM DC – 6 GHz High Power SPDT Switch



# **Application Circuit**



This switch can be configured as a Single Pole, Single Throw (SPST) by terminating one unused RF Out port with a 50 Ohm load.

Bias-up Procedure	Bias-down Procedure
Vc1 or Vc2 set to -40 V (see Function Table below for RF Path)	Turn off RF supply
Vc2 or Vc1 set to 0 V (see Function Table below for RF Path)	Turn Vc1 or Vc2 to 0V
Apply RF signal to RF Input	Turn Vc2 or Vc1 to 0 V

#### **Function Table**

RF Path	State	Vc1	Vc2
DE In to DE Out1 (50 Ohm load to DE Out2)	On-State (Insertion Loss)	0 V	-40 V
KF III to KF Out1 (50 Onill load to KF Out2)	Off-State (Isolation)	-40 V	0 V
DE la te DE Out2 (50 Ohm lood te DE Out1)	On-State (Insertion Loss)	-40 V	0 V
KF III to KF Out2 (50 Onm load to KF Out1)	Off-State (Isolation)	0 V	-40 V

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# TGS2351-SM DC – 6 GHz High Power SPDT Switch



# **Pin Description**



Pin	Symbol	Description
1, 2, 5, 6, 7, 9, 12, 13, 18, 19, 22, and 24	GND	No internal connection; must be grounded on PCB
3 and 4	RF In	Input, matched to 50 ohms, DC coupled
9, 22	GND	Connected to GND paddle (pin 25) must be grounded on PCB to improve isolation
8	Vc2	Control voltage #2; see Application Circuit on page 7 as an example
10 and 11	RF Out2	Output #2, matched to 50 ohms, DC coupled
14, 15, 16, and 17	N/C	No internal connection; can be grounded or left open
20 and 21	RF Out1	Output #1, matched to 50 ohms, DC coupled
23	Vc1	Control voltage #1; see Application Circuit on page 7 as an example
25	GND	Backside Paddle. Multiple vias should be employed to minimize inductance and thermal resistance; see Mounting Configuration on page 11 for suggested footprint.



### **Applications Information**

# PC Board Layout

Top RF layer is 0.010" thick Rogers 4350,  $\epsilon_r = 3.66$ . Metal layers are 0.5-oz copper. Microstrip 50  $\Omega$  line detail: width = 0.0217".

The pad pattern shown has been developed and tested for optimized assembly at TriQuint Semiconductor. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from company to company, careful process development is recommended.

For further technical information, refer to the <u>TGS2351-SM</u> Product Information page.





#### **Mechanical Information**

#### **Package Information and Dimensions**

All dimensions are in millimeters.



This package is lead-free/RoHS-compliant with a Aluminum Nitride base (AlN), and the plating material on the leads is Electroless Gold (Au) over Electroless nickel (Ni). It is compatible with both lead-free (maximum 260 °C reflow temperature) and tin-lead (maximum 245 °C reflow temperature) soldering processes.

The TGS2351-SM will be marked with the "2351" designator and a lot code marked below the part designator. The "YY" represents the last two digits of the year the part was manufactured, the "WW" is the work week, and the "MXXX" is a supplier code and partial batch ID.



# **Mechanical Information (cont.)**

# **Mounting Configuration**

All dimensions are in millimeters (inches).

Notes:

- 1. A heatsink underneath the area of the PCB for the mounted device is recommended for proper thermal operation.
- 2. Ground / thermal vias are critical for the proper performance of this device.

Vias have a final plated thru diameter of .203 mm (.008").





#### **Product Compliance Information**

#### **ESD** Information



ESD Rating:	Class 1B
Value:	Passes $\geq 500$ V min.
Test:	Human Body Model (HBM)
Standard:	JEDEC Standard JESD22-A114

# **MSL** Rating

Level 1 at +260 °C convection reflow The part is rated Moisture Sensitivity Level TBD at 260°C per JEDEC standard IPC/JEDEC J-STD-020.

# ECCN

US Department of Commerce EAR99

# **Recommended Soldering Temperature Profile**

#### 300 $t_{\text{within 5C of peak temp}}$ =30s max T<sub>peak</sub>=260C +0/-5C 3 C/s max ramp 250 Tliquidus=217C Tpreheat<sub>max</sub>=200C 200 Temperature (C) 60s-150s 150 Tpreheat<sub>min</sub>=150C t<sub>preheat</sub>=60s-120s 100 6 C/s max ramp 3 C/s max ramp 50 t<sub>25C to peak temp</sub>=8 minutes max 0 0 60 120 180 240 300 Time (s)

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# Solderability

Compatible with the latest version of J-STD-020, Lead free solder,  $260^{\circ}$ 

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A ( $C_{15}H_{12}Br_40_2$ ) Free
- PFOS Free
- SVHC Free



### **Contact Information**

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

Web:	www.triguint.com	Tel:	+1.972.994.8465
Email:	info-sales@tqs.com	Fax:	+1.972.994.8504

For technical questions and application information:

Email: info-products@tqs.com

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